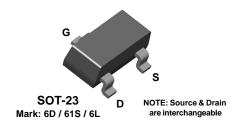


2N5457 2N5458 2N5459

MMBF5457 MMBF5458 MMBF5459





N-Channel General Purpose Amplifier

This device is a low level audio amplifier and switching transistors, and can be used for analog switching applications. Sourced from Process 55.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{DG}	Drain-Gate Voltage	25	V
V _{GS}	Gate-Source Voltage	- 25	V
I _{GF}	Forward Gate Current	10	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	N	Max	
		2N5457-5459	*MMBF5457-5459	
P_D	Total Device Dissipation	625	350	mW
	Derate above 25°C	5.0	2.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W

^{*}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

¹⁾ These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

N-Channel General Purpose Amplifier

(continued)

	ectrical Characteri

TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units

OFF CHARACTERISTICS

V _{(BR)GSS}	Gate-Source Breakdown Voltage	$I_G = 10 \mu A, V_{DS} = 0$		- 25			V
I _{GSS}	Gate Reverse Current	$V_{GS} = -15 \text{ V}, V_{DS} = 0$ $V_{GS} = -15 \text{ V}, V_{DS} = 0, T_{A} = 0$	100°C			- 1.0 - 200	nA nA
V _{GS(off)}	Gate-Source Cutoff Voltage	$V_{DS} = 15 \text{ V}, V_{DS} = 0, T_{A} = 0$ $V_{DS} = 15 \text{ V}, I_{D} = 10 \text{ nA}$	5457 5458	- 0.5 - 1.0		- 6.0 - 7.0	V
V _{GS}	Gate-Source Voltage	V _{DS} = 15 V, I _D = 100 μA V _{DS} = 15 V, I _D = 200 μA V _{DS} = 15 V, I _D = 400 μA	5459 5457 5458 5459	- 2.0	- 2.5 - 3.5 - 4.5	- 8.0	V V V

ON CHARACTERISTICS

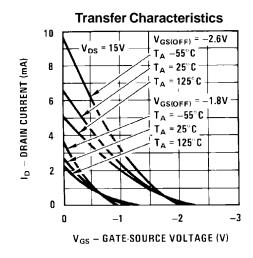
I _{DSS}	Zero-Gate Voltage Drain Current*	$V_{DS} = 15 \text{ V}, V_{GS} = 0$	5457	1.0	3.0	5.0	mΑ
			5458	2.0	6.0	9.0	mΑ
			5459	4.0	9.0	16	mΑ

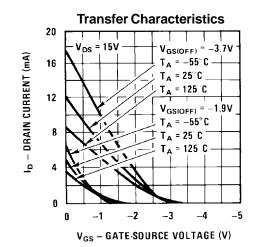
SMALL SIGNAL CHARACTERISTICS

9 _{fs}	Forward Transfer Conductance*	$V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ kHz}$				
		5457 5458 5459	1000 1500 2000		5000 5500 6000	μmhos μmhos μmhos
gos	Output Conductance*	$V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ kHz}$		10	50	μmhos
Ciss	Input Capacitance	V _{DS} = 15 V, V _{GS} = 0, f = 1.0 MHz		4.5	7.0	pF
Crss	Reverse Transfer Capacitance	$V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ MHz}$		1.5	3.0	pF
NF	Noise Figure	$V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ kHz}, R_G = 1.0 \text{ megohm}, BW = 1.0 \text{ Hz}$			3.0	dB

^{*}Pulse Test: Pulse Width ≤ 300 ms, Duty Cycle ≤ 2%

Typical Characteristics

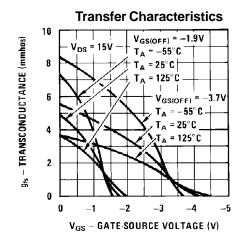


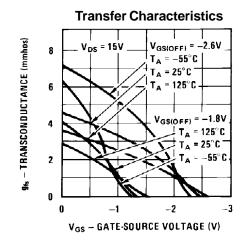


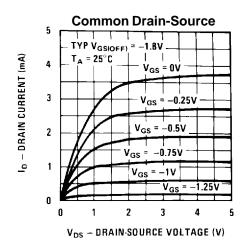
N-Channel General Purpose Amplifier

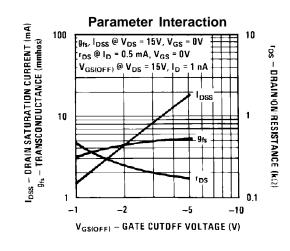
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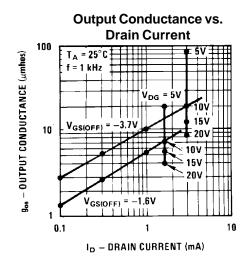
Typical Characteristics (continued)

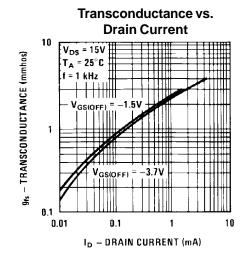








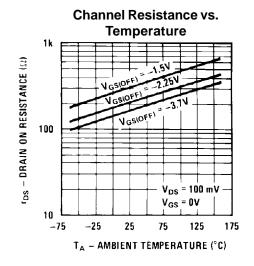


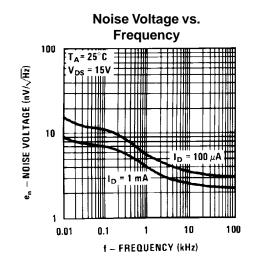


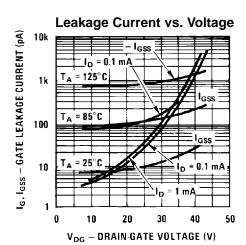
N-Channel General Purpose Amplifier

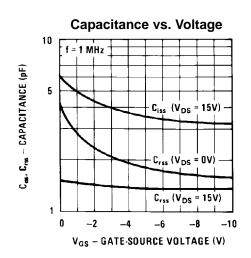
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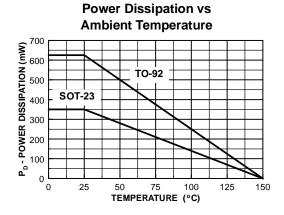
Typical Characteristics (continued)











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